



Heterojunction Bipolar Transistor Technology (InGaP HBT)

Broadband High Linearity Amplifier

The MMG3005NT1 is a General Purpose Amplifier that is internally prematched and designed for a broad range of Class A, small-signal, high linearity, general purpose applications. It is suitable for applications with frequencies from 800 to 2200 MHz such as Cellular, PCS, WLL, PHS, VHF, UHF, UMTS and general small-signal RF.

Features

- Frequency: 800-2200 MHz
- P1dB: 30 dBm @ 2140 MHz
- Small-Signal Gain: 15 dB @ 2140 MHz
- Third Order Output Intercept Point: 47 dBm @ 2140 MHz
- Single 5 Volt Supply
- Internally Prematched to 50 Ohms
- Pb-Free Leads. RoHS Compliant.
- In Tape and Reel. T1 Suffix = 1000 Units per 12 mm, 7 inch Reel.

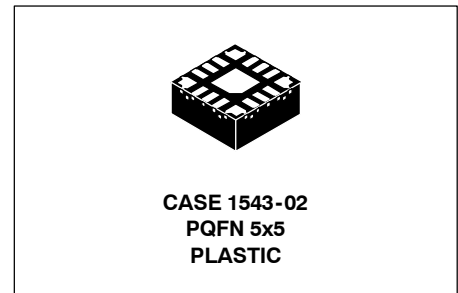


Table 1. Typical Performance (1)

Characteristic	Symbol	900 MHz	1960 MHz	2140 MHz	Unit
Small-Signal Gain (S21)	G _p	18.5	15.5	15	dB
Input Return Loss (S11)	IRL	-14	-10	-11	dB
Output Return Loss (S22)	ORL	-12	-7	-7	dB
Power Output @1dB Compression	P1db	30	30	30	dBm
Third Order Output Intercept Point	IP3	47	47	47	dBm

1. V_{DC} = 5 Vdc, T_C = 25°C, 50 ohm system

Table 2. Maximum Ratings

Rating	Symbol	Value	Unit
Supply Voltage (2)	V _{DC}	6	V
Supply Current (2)	I _{DC}	600	mA
RF Input Power	P _{in}	18	dBm
Storage Temperature Range	T _{stg}	-65 to +150	°C
Junction Temperature (3)	T _J	150	°C

2. Continuous voltage and current applied to device.

3. For reliable operation, the junction temperature should not exceed 150°C.

Table 3. Thermal Characteristics (V_{DC} = 5 Vdc, I_{DC} = 480 mA, T_C = 25°C)

Characteristic	Symbol	Value (4)	Unit
Thermal Resistance, Junction to Case	R _{θJC}	21.5	°C/W

4. Refer to AN1955, *Thermal Measurement Methodology of RF Power Amplifiers*. Go to <http://www.freescale.com/rf>. Select Documentation/Application Notes - AN1955.

Table 4. Electrical Characteristics ($V_{DC} = 5 \text{ Vdc}$, 2140 MHz, $T_C = 25^\circ\text{C}$, 50 ohm system, in Freescale Application Circuit)

Characteristic	Symbol	Min	Typ	Max	Unit
Small-Signal Gain (S21)	G_p	14	15	—	dB
Input Return Loss (S11)	IRL	—	-11	—	dB
Output Return Loss (S22)	ORL	—	-7	—	dB
Power Output @ 1dB Compression	P1dB	—	30	—	dBm
Third Order Output Intercept Point	IP3	—	47	—	dBm
Noise Figure	NF	—	5	—	dB
Supply Current (1)	I_{DC}	455	480	520	mA
Supply Voltage (1)	V_{DC}	—	5	—	V

1. For reliable operation, the junction temperature should not exceed 150°C .

Table 5. Functional Pin Description

Name	Pin Number	Description
RF _{in}	3, 4	RF input for the power amplifier. This pin is DC-coupled and requires a DC-blocking series capacitor.
RF _{OUT} / V _{CC}	10, 11, 12	RF output for the power amplifier. This pin is DC-coupled and requires a DC-blocking series capacitor.
V _{CC}	14	Collector voltage supply.
V _{BA}	16	Bias voltage supply.
GND	Backside Center Metal	The center metal base of the PQFN package provides both DC and RF ground as well as heat sink contact for the power amplifier.

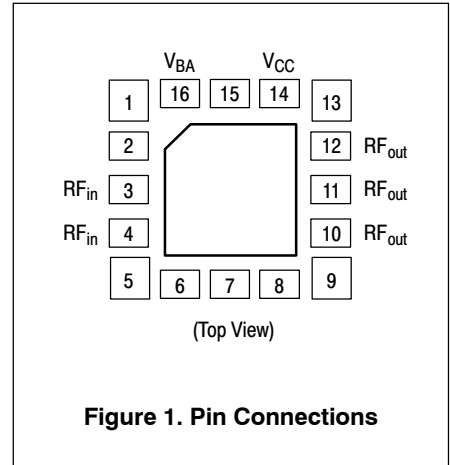


Table 6. ESD Protection Characteristics

Test Methodology	Class
Human Body Model (per JESD 22-A114)	1A (Minimum)
Machine Model (per EIA/JESD 22-A115)	A (Minimum)
Charge Device Model (per JESD 22-C101)	IV (Minimum)

Table 7. Moisture Sensitivity Level

Test Methodology	Rating	Package Peak Temperature	Unit
Per JESD 22-A113, IPC/JEDEC J-STD-020	3	260	°C

50 OHM TYPICAL CHARACTERISTICS

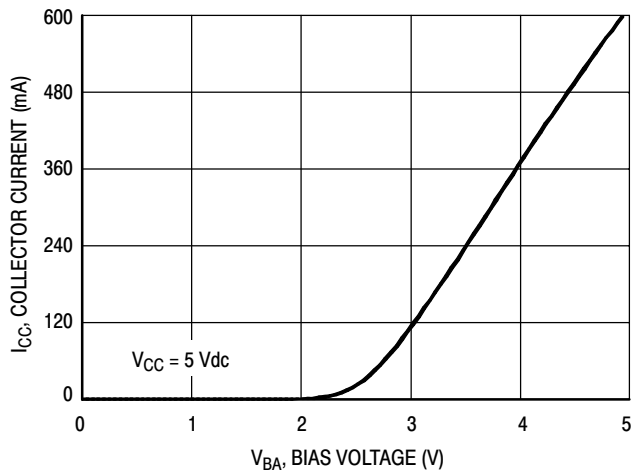
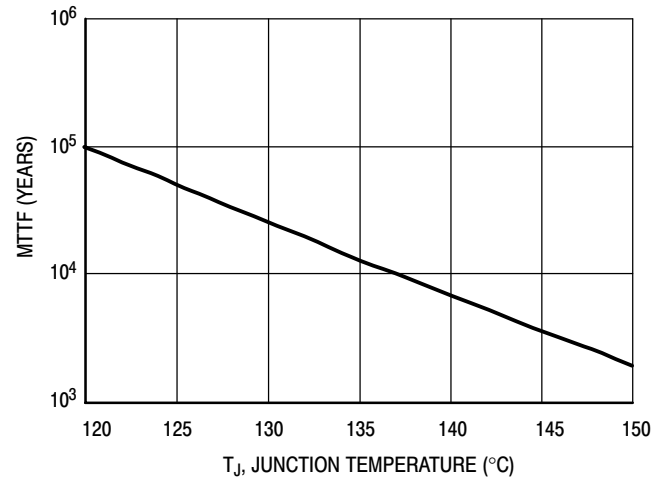


Figure 2. Collector Current versus Bias Voltage



NOTE: The MTTF is calculated with $V_{DC} = 5$ Vdc, $I_{DC} = 480$ mA

Figure 3. MTTF versus Junction Temperature

50 OHM APPLICATION CIRCUIT: 900 MHz

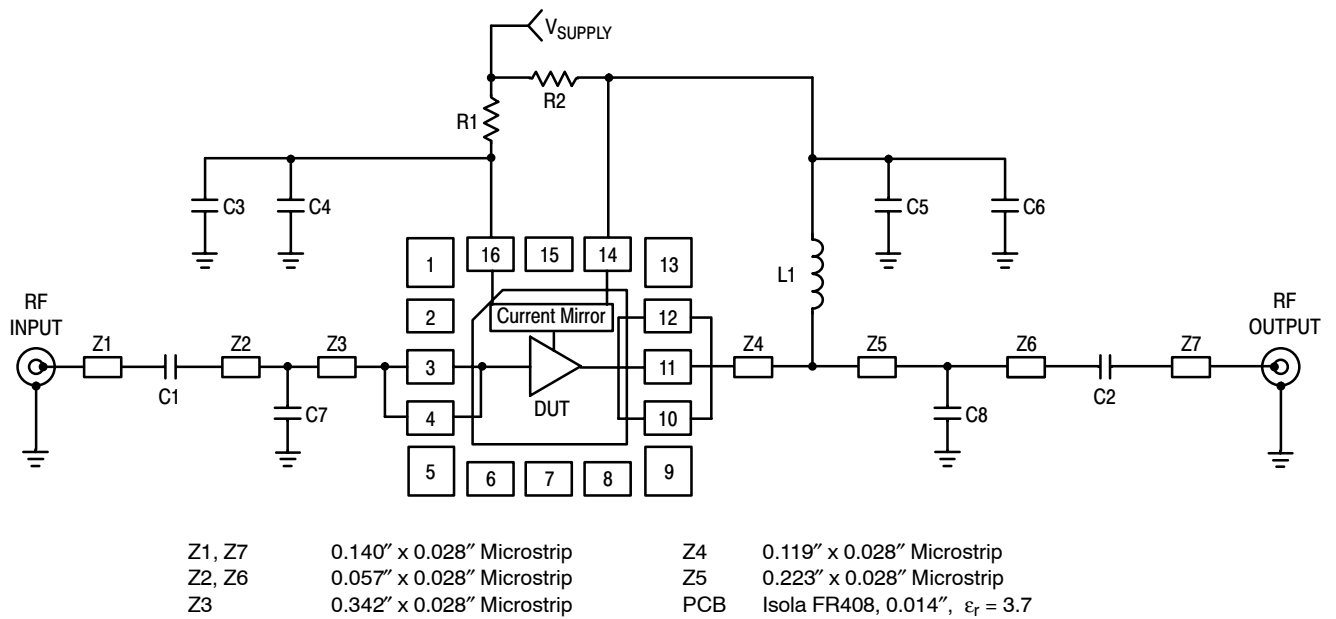


Figure 4. 50 Ohm Test Circuit Schematic

Table 8. 50 Ohm Test Circuit Component Designations and Values

Part	Description	Part Number	Manufacturer
C1, C2	15 pF Chip Capacitors	ECUV1H150JCV	Panasonic
C3, C5	0.01 μ F Chip Capacitors	0603A103JAT2A	AVX
C4, C6	0.1 μ F Chip Capacitors	0603A102JAT2A	AVX
C7	6.8 pF Chip Capacitor	06035J6R8BBT	AVX
C8	5.6 pF Chip Capacitor	06035J5R6BBT	AVX
L1	15 nH Chip Inductor	1008CS-150XJB	Coilcraft
R1	33 Ω Chip Resistor		
R2	0 Ω Chip Resistor		

50 OHM APPLICATION CIRCUIT: 900 MHz

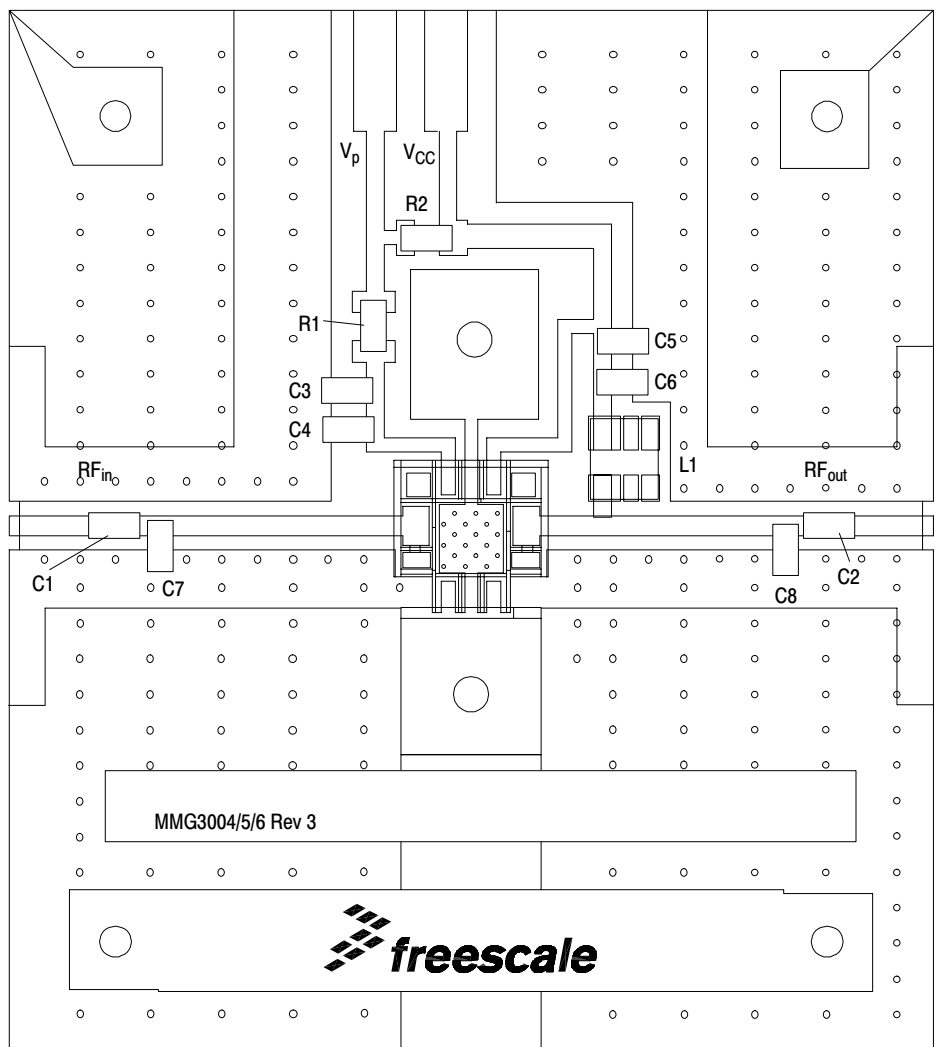


Figure 5. 50 Ohm Test Circuit Component Layout

50 OHM TYPICAL CHARACTERISTICS: 900 MHz

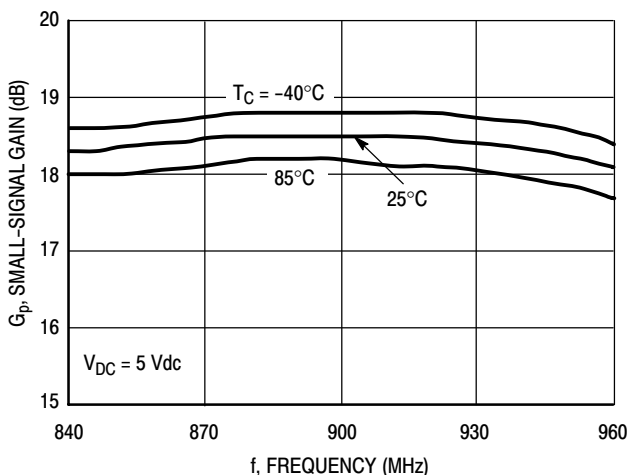


Figure 6. Small-Signal Gain (S21) versus Frequency

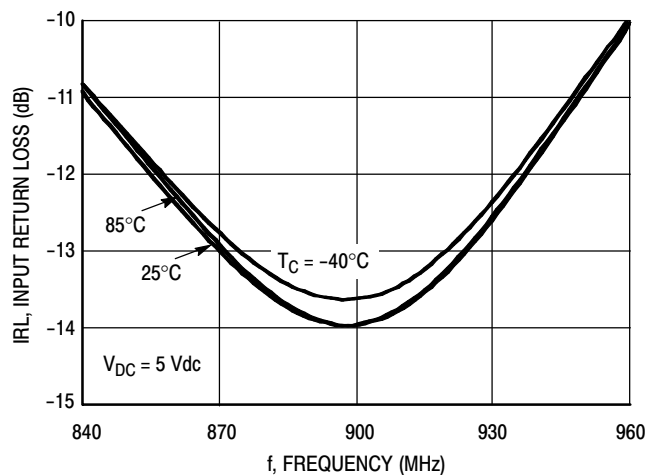


Figure 7. Input Return Loss (S11) versus Frequency

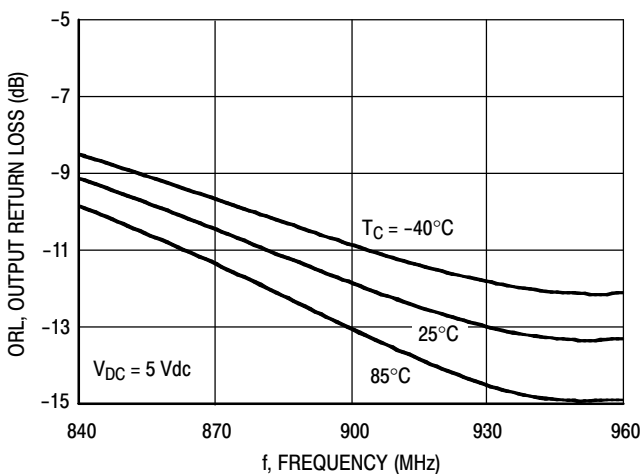


Figure 8. Output Return Loss (S22) versus Frequency

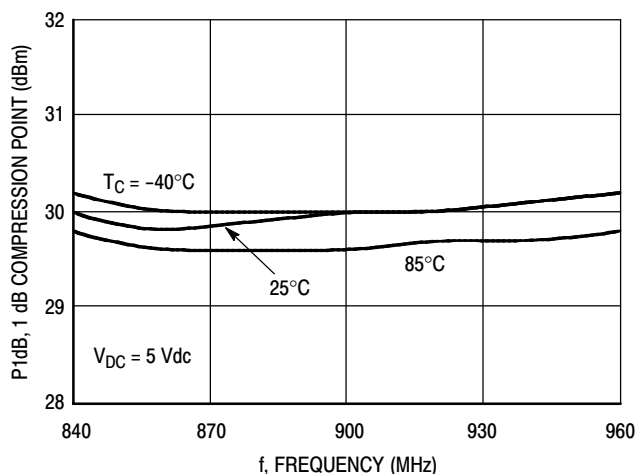


Figure 9. P1dB versus Frequency

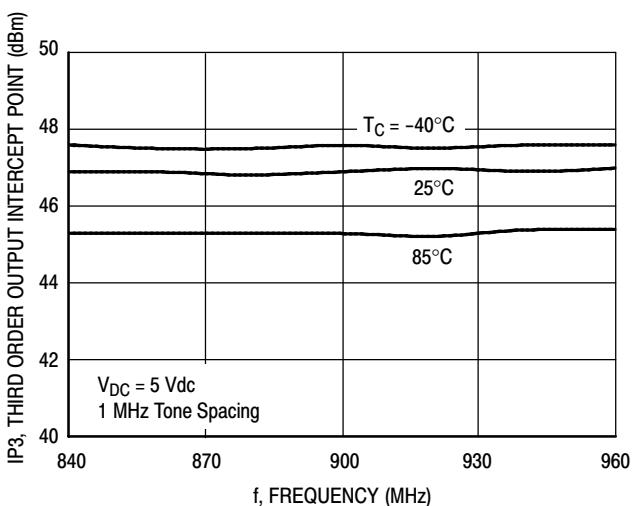


Figure 10. Third Order Output Intercept Point versus Frequency

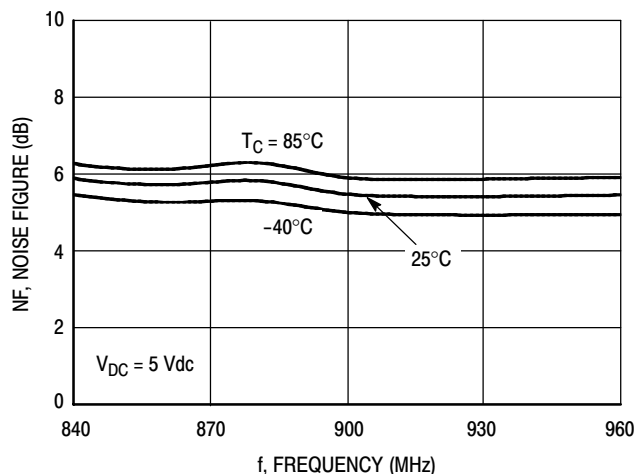


Figure 11. Noise Figure versus Frequency

50 OHM TYPICAL CHARACTERISTICS: 900 MHz

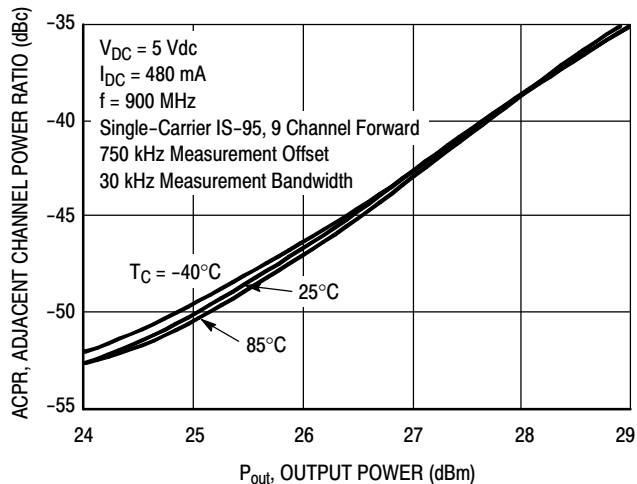


Figure 12. IS-95 Adjacent Channel Power Ratio versus Output Power

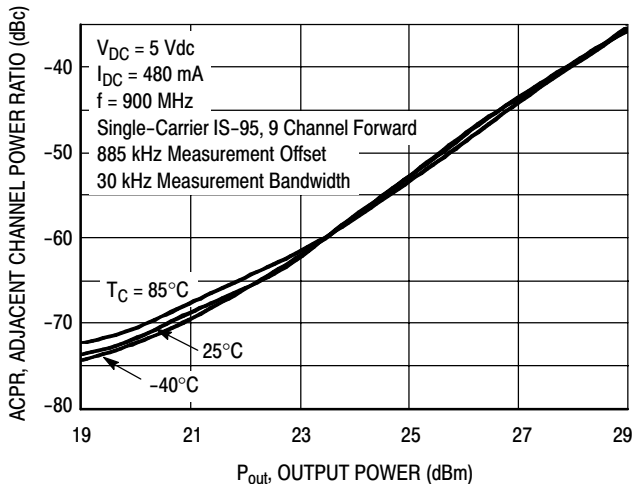


Figure 13. IS-95 Adjacent Channel Power Ratio versus Output Power

50 OHM APPLICATION CIRCUIT: 1800-2200 MHz

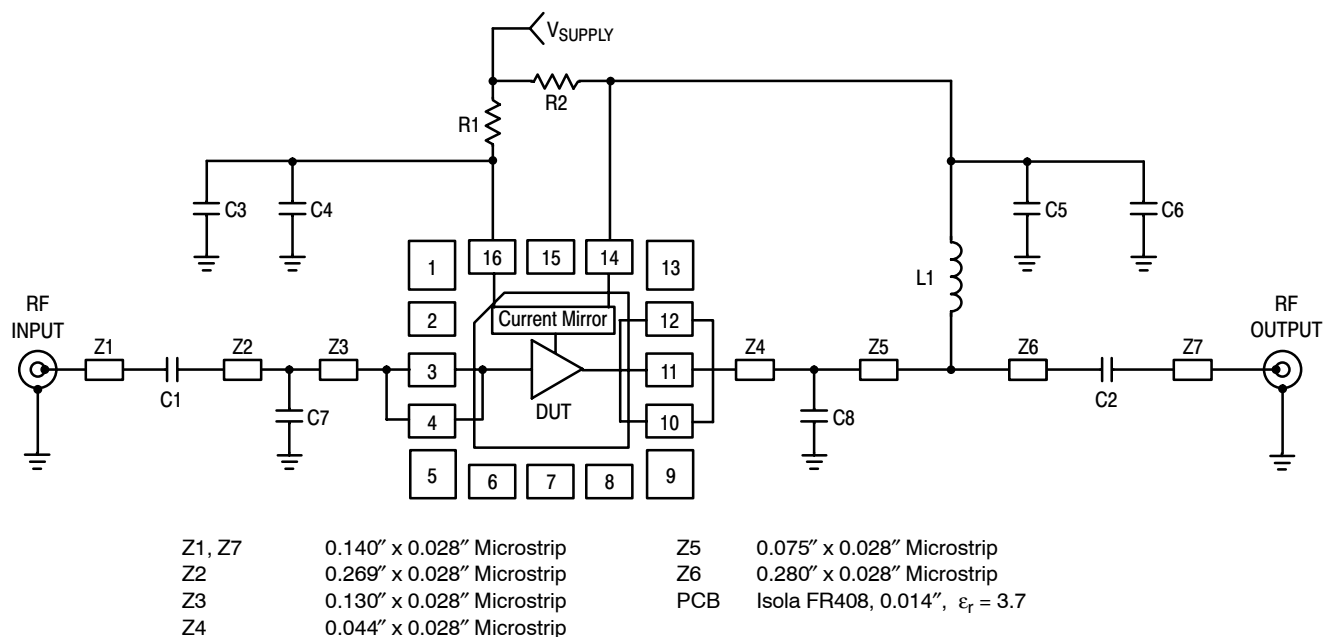


Figure 14. 50 Ohm Test Circuit Schematic

Table 9. 50 Ohm Test Circuit Component Designations and Values

Part	Description	Part Number	Manufacturer
C1	15 pF Chip Capacitor	ECUV1H150JCV	Panasonic
C2	1.8 pF Chip Capacitor	06035J1R8BBT	AVX
C3, C5	0.01 μ F Chip Capacitors	0603A103JAT2A	AVX
C4, C6	0.1 μ F Chip Capacitors	0603A102JAT2A	AVX
C7	2.7 pF Chip Capacitor	06035J2R7BBT	AVX
C8	1.2 pF Chip Capacitor	06035J1R2BBT	AVX
L1	15 nH Chip Inductor	1008CS-150XJB	Coilcraft
R1	33 Ω Chip Resistor		
R2	0 Ω Chip Resistor		

50 OHM APPLICATION CIRCUIT: 1800-2200 MHz

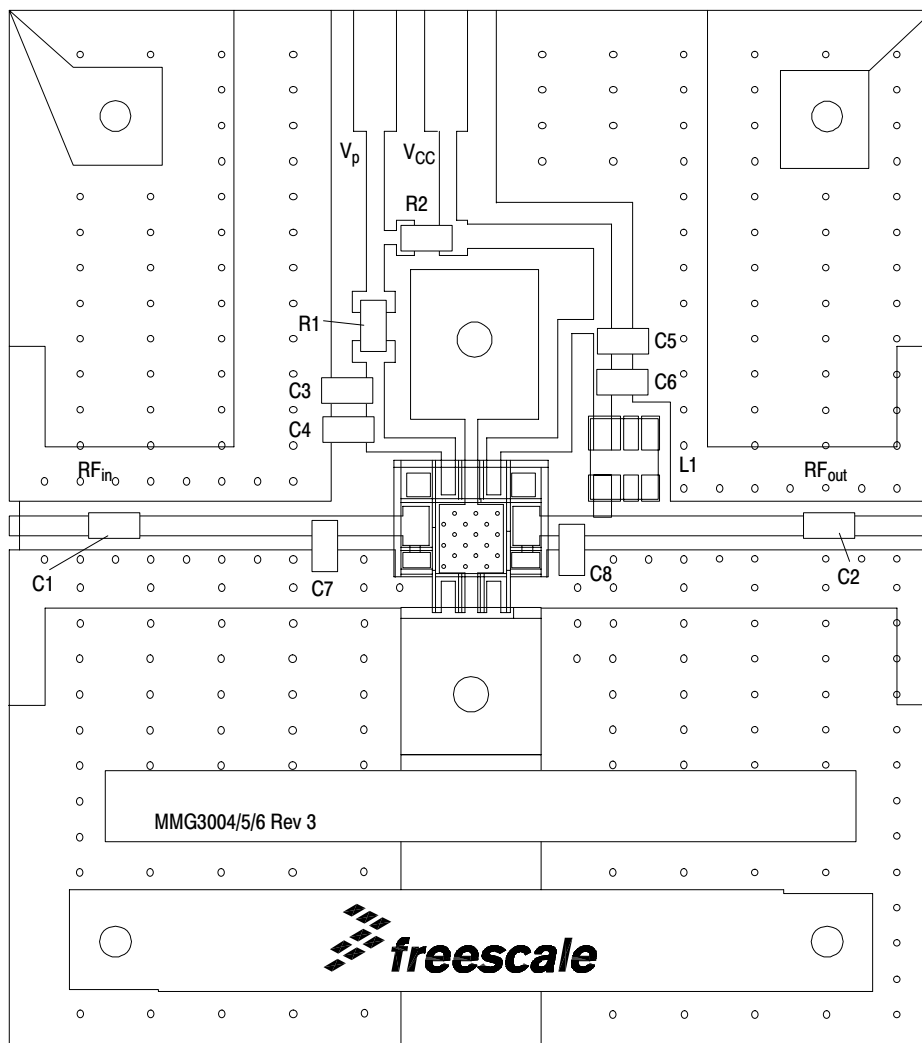


Figure 15. 50 Ohm Test Circuit Component Layout

50 OHM TYPICAL CHARACTERISTICS: 1800-2200 MHz

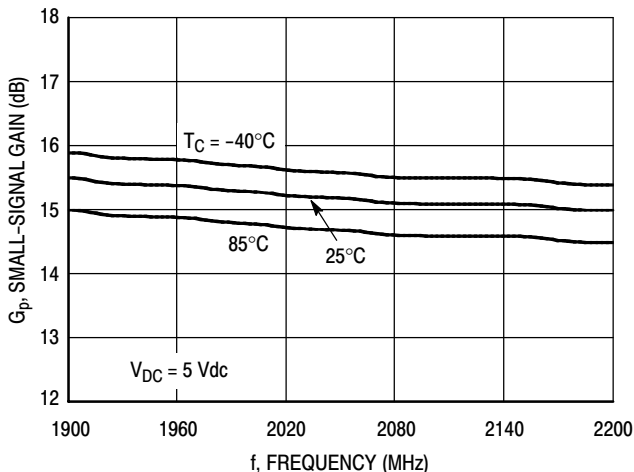


Figure 16. Small-Signal Gain (S21) versus Frequency

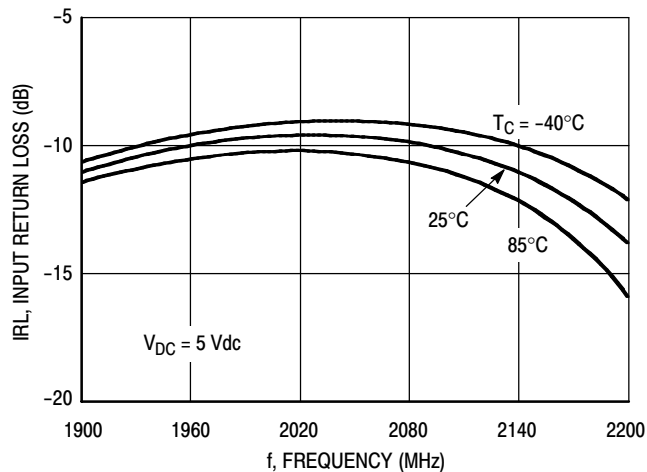


Figure 17. Input Return Loss (S11) versus Frequency

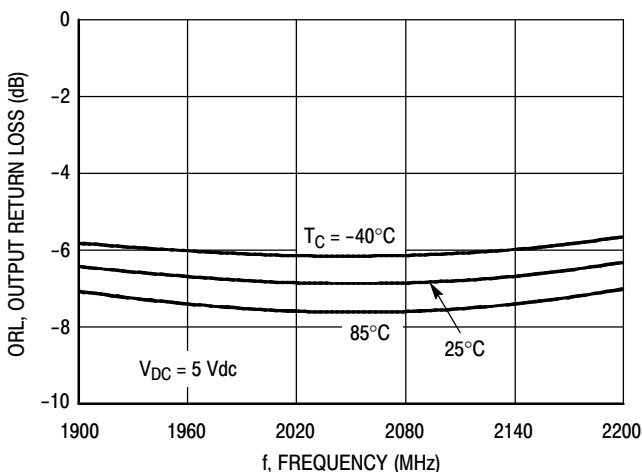


Figure 18. Output Return Loss (S22) versus Frequency

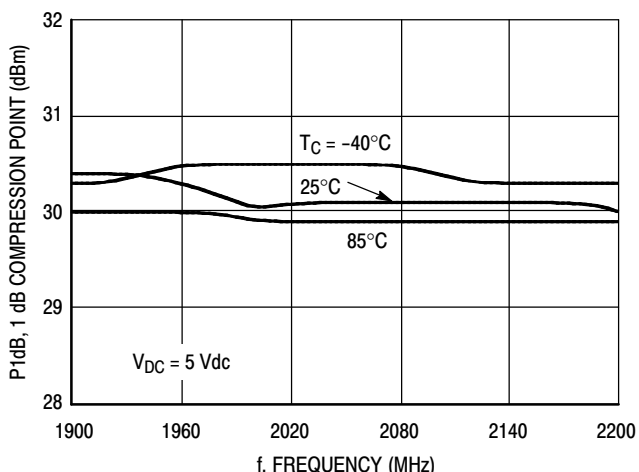


Figure 19. P1dB versus Frequency

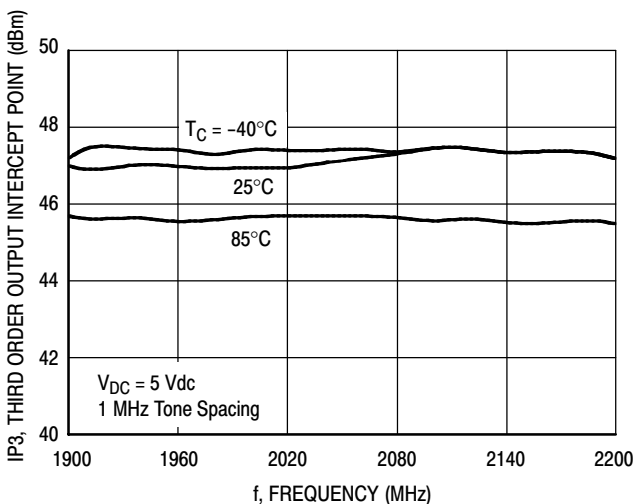


Figure 20. Third Order Output Intercept Point versus Frequency

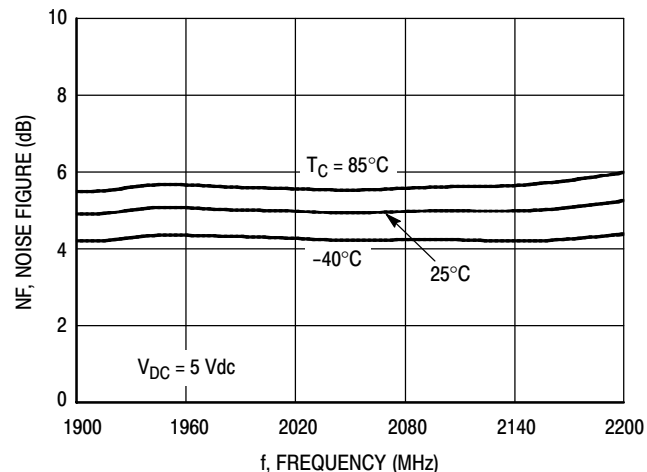


Figure 21. Noise Figure versus Frequency

50 OHM TYPICAL CHARACTERISTICS: 1800-2200 MHz

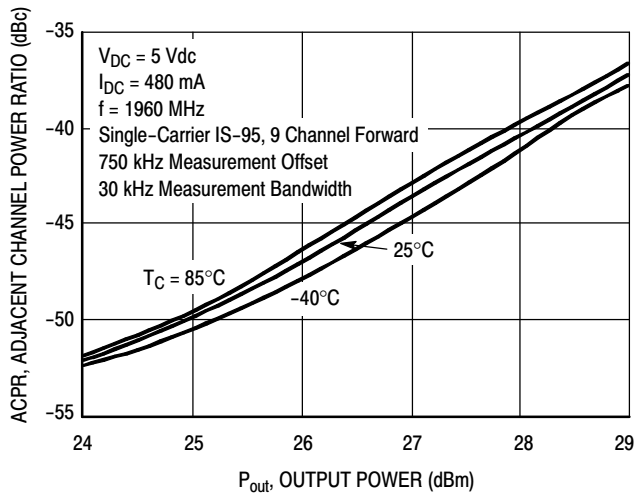


Figure 22. IS-95 Adjacent Channel Power Ratio versus Output Power

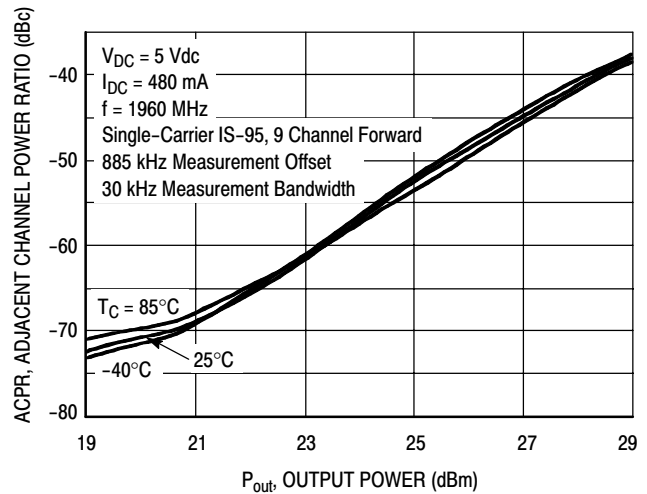


Figure 23. IS-95 Adjacent Channel Power Ratio versus Output Power

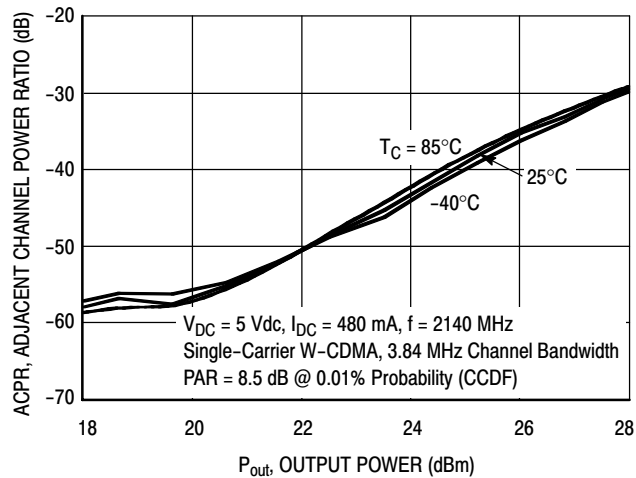


Figure 24. Single-Carrier W-CDMA Adjacent Channel Power Ratio versus Output Power

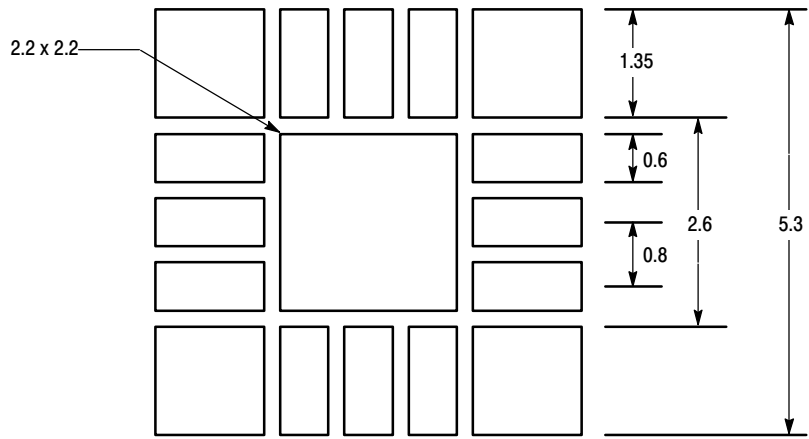
50 OHM TYPICAL CHARACTERISTICS

Table 10. Class A Common Emitter S-Parameters at $V_{DC} = 5 \text{ Vdc}$, $I_{DC} = 480 \text{ mA}$, $T_C = 25^\circ\text{C}$

f GHz	S ₁₁		S ₂₁		S ₁₂		S ₂₂	
	S ₁₁	∠φ	S ₂₁	∠φ	S ₁₂	∠φ	S ₂₂	∠φ
0.25	0.70575	-173.81	5.06022	143.91	0.00976	-49.75	0.84913	174.65
0.3	0.73140	-174.91	4.79122	137.40	0.00866	-46.60	0.84273	173.16
0.35	0.75442	-176.26	4.52885	131.51	0.00773	-43.76	0.83759	172.12
0.4	0.77553	-177.67	4.27831	126.11	0.00689	-40.58	0.83409	171.28
0.45	0.79364	-179.04	4.03762	121.18	0.00618	-36.61	0.83042	170.63
0.5	0.80933	179.58	3.82617	116.75	0.00565	-31.68	0.83214	170.43
0.55	0.82301	178.27	3.62033	112.46	0.00523	-26.34	0.83079	169.99
0.6	0.83429	177.07	3.43310	108.55	0.00494	-20.59	0.82956	169.83
0.65	0.84357	175.98	3.26377	104.82	0.00478	-15.13	0.82812	169.78
0.7	0.85132	174.99	3.10735	101.29	0.00468	-10.28	0.82590	169.86
0.75	0.85696	174.16	2.96322	97.96	0.00459	-5.76	0.82489	170.15
0.8	0.86176	173.35	2.82568	94.86	0.00454	-1.51	0.82589	170.57
0.85	0.86572	172.60	2.70160	92.31	0.00452	3.52	0.82783	171.07
0.9	0.86813	171.85	2.60468	90.11	0.00455	7.99	0.83010	171.50
0.95	0.86945	171.15	2.53732	88.04	0.00475	12.64	0.83192	172.00
1	0.86974	170.42	2.48944	85.86	0.00498	15.23	0.83202	172.45
1.05	0.86842	169.66	2.45821	83.61	0.00517	16.96	0.83128	172.96
1.1	0.86533	168.91	2.44429	81.27	0.00537	18.37	0.82923	173.50
1.15	0.86095	168.14	2.44811	78.81	0.00562	19.48	0.82679	174.01
1.2	0.85480	167.25	2.46595	76.18	0.00589	19.73	0.82313	174.63
1.25	0.84684	166.25	2.49650	73.39	0.00614	19.47	0.81800	175.29
1.3	0.83707	165.18	2.54318	70.39	0.00639	18.66	0.81154	176.08
1.35	0.82469	164.00	2.60413	67.17	0.00664	17.14	0.80396	176.98
1.4	0.80971	162.76	2.68767	63.69	0.00686	15.10	0.79812	177.98
1.45	0.79087	161.42	2.79189	59.73	0.00707	12.45	0.79179	178.83
1.5	0.76847	160.03	2.91082	55.24	0.00723	8.99	0.78258	179.68
1.55	0.74126	158.60	3.04944	50.25	0.00735	4.62	0.77256	-179.28
1.6	0.70933	157.30	3.20126	44.67	0.00737	-0.89	0.76200	-178.18
1.65	0.67261	156.25	3.36356	38.42	0.00727	-7.59	0.75243	-176.93
1.7	0.63202	155.73	3.53052	31.45	0.00702	-15.85	0.74435	-175.63
1.75	0.59058	156.13	3.69596	23.72	0.00657	-25.99	0.73950	-174.33
1.8	0.55219	157.76	3.84647	15.21	0.00592	-38.78	0.73766	-173.25
1.85	0.53906	175.46	3.84639	5.98	0.00493	-55.47	0.74863	173.64
1.9	0.55077	-178.72	3.76728	-3.57	0.00394	-78.20	0.76239	172.14
1.95	0.58350	-174.08	3.61364	-13.31	0.00325	-110.26	0.77658	170.13
2	0.63044	-171.29	3.40538	-22.98	0.00325	-147.37	0.78891	167.72
2.05	0.68283	-170.32	3.15278	-32.28	0.00389	-177.72	0.79795	164.96
2.1	0.73327	-170.78	2.87824	-41.07	0.00480	161.34	0.80422	162.03
2.15	0.77875	-172.14	2.60183	-49.24	0.00576	146.52	0.80618	159.04
2.2	0.81666	-174.06	2.33461	-56.78	0.00658	135.49	0.80601	156.02
2.25	0.84807	-176.25	2.08577	-63.69	0.00728	126.95	0.80299	153.08
2.3	0.87279	-178.55	1.85911	-70.01	0.00782	120.20	0.79865	150.21
2.35	0.89261	179.07	1.65704	-75.82	0.00823	114.85	0.79341	147.45
2.4	0.90758	176.70	1.47812	-81.19	0.00851	110.74	0.78715	144.80
2.45	0.91984	174.31	1.32091	-86.22	0.00868	107.68	0.78067	142.25

Table 10. Class A Common Emitter S-Parameters at $V_{DC} = 5$ Vdc, $I_{DC} = 480$ mA, $T_C = 25^\circ\text{C}$ (continued)

f GHz	S_{11}		S_{21}		S_{12}		S_{22}	
	$ S_{11} $	$\angle \phi$	$ S_{21} $	$\angle \phi$	$ S_{12} $	$\angle \phi$	$ S_{22} $	$\angle \phi$
2.5	0.92917	171.99	1.18240	-90.93	0.00876	105.84	0.77298	139.76
2.55	0.93606	169.65	1.06136	-95.41	0.00878	105.17	0.76528	137.41
2.6	0.94249	167.38	0.95471	-99.69	0.00880	105.76	0.75557	135.15
2.65	0.94659	165.17	0.86109	-103.83	0.00882	107.70	0.74569	132.95
2.7	0.95002	163.00	0.77869	-107.89	0.00894	111.20	0.73387	130.86
2.75	0.95243	160.86	0.70576	-111.91	0.00932	116.13	0.72034	128.82
2.8	0.95418	158.70	0.64070	-115.96	0.01006	121.98	0.70405	126.97
2.85	0.95534	156.67	0.58229	-120.08	0.01141	127.95	0.68401	125.22
2.9	0.95570	154.64	0.52887	-124.40	0.01358	132.34	0.65990	123.77
2.95	0.95565	152.68	0.47907	-128.91	0.01662	134.33	0.63014	122.76
3	0.95487	150.86	0.43144	-133.65	0.02061	133.72	0.59605	122.51



NOTES:

1. THERMAL AND RF GROUNDING CONSIDERATIONS SHOULD BE USED IN PCB LAYOUT DESIGN.
2. DEPENDING ON PCB DESIGN RULES, AS MANY VIAS AS POSSIBLE SHOULD BE PLACED ON THE BACKSIDE CENTER METAL GROUND LANDING PATTERN.
3. REFER TO FREESCALE APPLICATION NOTE AN2467 FOR ADDITIONAL PQFN PCB GUIDELINES.

Figure 25. Recommended Mounting Configuration



NOTES



NOTES



NOTES

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